

PNZ147 (PN147)

Silicon NPN Phototransistor

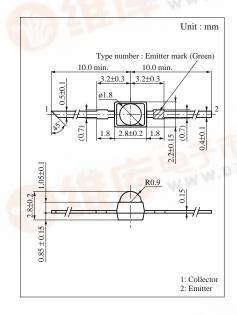
For optical control systems

Features

- High sensitivity
- Wide spectral sensitivity, matched to GaAs LEDs
- Fast response : t_r , $t_f = 3 \mu s$ (typ.)
- Small size designed for easier mounting to printed circuit board

■ Absolute Maximum Ratings (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit |
|-------------------------------|------------------|-------------|------|
| Collector to emitter voltage | V _{CEO} | 20 | V |
| Emitter to collector voltage | V _{ECO} | 5 | V |
| Collector current | I_{C} | 20 | mA |
| Collector power dissipation | P _C | 50 | mW |
| Operating ambient temperature | Topr | -25 to +85 | °C |
| Storage temperature | T _{stg} | -30 to +100 | °C |

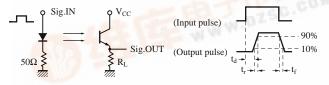


Electro-Optical Characteristics ($Ta = 25^{\circ}C$)

| Parameter | Symbol | Conditions | | typ | max | Unit |
|------------------------------|------------------------|--|---|------|-----|------|
| Dark current | I _{CEO} | $V_{CE} = 10V$ | | 0.01 | 0.5 | μΑ |
| Collector photo current | I _{CE(L)1} *3 | $V_{CE} = 10V, L = 2 lx^{*1}$ | 3 | 12 | | μΑ |
| | I _{CE(L)2} | $V_{CE} = 10V, L = 500 lx^{*1}$ | | 3.5 | | mA |
| Peak sensitivity wavelength | λ_{P} | $V_{CE} = 10V$ | | 800 | | nm |
| Acceptance half angle | θ | Measured from the optical axis to the half power point | | 24 | - 4 | deg. |
| Response time | t_r, t_f^{*2} | $V_{CC} = 10V, I_{CE(L)} = 5mA, R_L = 100\Omega$ | | 3 | 10 | μs |
| Collector saturation voltage | V _{CE(sat)} | $I_{CE(L)} = 1 \text{mA}, L = 1000 \text{ lx}^{*1}$ | | 0.2 | 0.5 | V |

^{*1} Measurements were made using a tungsten lamp (color temperature T = 2856K) as a light source.

^{*2} Switching time measurement circuit

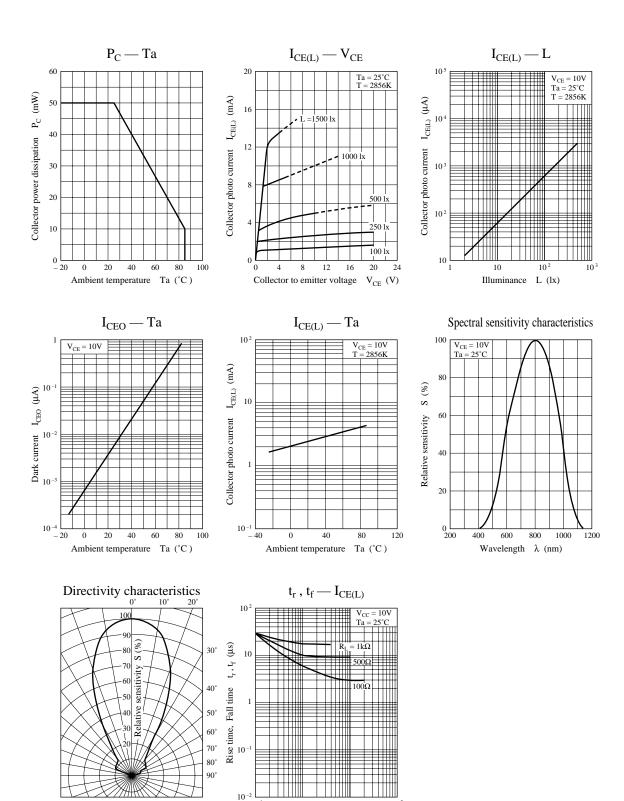


- t_d: Delay time
- $\rm t_r$: Rise time (Time required for the collector photo current to increase from 10% to 90% of its final value)
- t_f: Fall time (Time required for the collector photo current to decrease from 90% to 10% of its initial value)

*3 I_{CE(L)} Classifications

| _ | (-) | | | | | |
|-----|------------|-------------|-------------|-------|--|--|
| 200 | Class | Q | R | S | | |
| 0 | 找CELL PHAF | 3.0 to 11.0 | 7.0 to 24.0 | >16.0 | | |
| | | | | | | |

Phototransistors PNZ147



 $Collector\ photo\ current \quad I_{CE(L)}\ \ (mA)$

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